L Number	Hits		DB	Time stamp
1	117	1 1	USPAT;	2004/07/01 15:00
		rom or prom or mosfet or fet or eeprom or	US-PGPUB;	
		nmos or pmos or eprom) and (gate) near8	EPO; JPO;	
		(tungsten adj silicide or wsi or w adj si)	DERWENT;	
		near8 (titanium adj silicide or tisi or ti	IBM_TDB	
_		adj si)		
2	5	\	USPAT;	2004/07/01 15:03
		rom or prom or mosfet or fet or eeprom or	US-PGPUB;	
İ		nmos or pmos or eprom) and (gate) near10	EPO; JPO;	
		(tungsten adj silicide or wsi or w adj si)	DERWENT;	
		near4 barrier same (titanium adj silicide or	IBM_TDB	
_		tisi or ti adj si)		
3	27	,	USPAT;	2004/07/01 15:07
		rom or prom or mosfet or fet or eeprom or	US-PGPUB;	
		nmos or pmos or eprom) and (gate) near5	EPO; JPO;	
		barrier near5 (tungsten adj silicide or wsi	DERWENT;	
		or w adj si)	IBM_TDB	
4	48	\	USPAT;	2004/07/01 15:38
		adj silicide or wsi or w adj si) with	US-PGPUB;	
		(titanium adj silicide or tisi or ti adj si)	EPO; JPO;	
			DERWENT;	
_			IBM_TDB	
5	30	, the same to the	USPAT;	2004/07/01 15:43
		near2 memory or dram) same sdram and (silicide) near4 gate	US-PGPUB;	
ł			EPO; JPO;	
			DERWENT;	
_			IBM_TDB	
6	20		USPAT;	2004/07/01 15:44
		near2 memory	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
_			IBM_TDB	
7	74	silicide and (edodram or edoram or edorom or	USPAT;	2004/07/01 15:54
		edo or edom)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
8	200		IBM_TDB	
	306		USPAT;	2004/07/01 16:10
		edoram or edorom or edo or edom)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
,	3.65		IBM_TDB	
9	165	5 (	USPAT;	2004/07/01 16:16
		edoram or edorom or edo or edom) with (dram	US-PGPUB;	
		or sdram or rom or prom or eeprom or eprom	EPO; JPO;	
,		or sram or ram)	DERWENT;	1
10	3	gate and govern and during and (-3-3)	IBM_TDB	0004/07/05
10	3	gate and source and drain and (edodram or	USPAT;	2004/07/01 16:16
		edoram or edorom or edo or edom) with (dram	US-PGPUB;	
		or sdram or rom or prom or eeprom or eprom	EPO; JPO;	
		or sram or ram) and silicide	DERWENT;	
_ 1	10	(gate on word noon line on wardline	IBM_TDB	0004/05/55
_	10	(gate or word near line or wordline or	USPAT;	2004/06/29 14:34
		transistor or fet or mosfet or sdram or rom	US-PGPUB;	
		or prom or dram) and (tungsten or titanium	EPO; JPO;	
		or w or ti or metal) near2 rich near2	DERWENT;	
		(silicide or salicide) with (oxygen or oxide	IBM_TDB	
		or oxidize or oxidized or oxidation or		
l		oxidization) with (nitride or nitrided or		
_	22	nitridation or nitradation)		
İ	22	(gate or word near line or wordline or	USPAT;	2004/06/29 15:15
I		transistor or fet or mosfet or sdram or rom	US-PGPUB;	
		or prom or dram) and (silicide or salicide	EPO; JPO;	
		or wsi or tisi) near3 (oxynitride or	DERWENT;	
		oxinitride or oxy-nitride) near5 (removal or	IBM_TDB	
		removing or removed or remove or etch or		
İ		etching or etched)		1
_		/1/45000564   1/45540504   1/55405555		
-	11	("4528066"   "4554050"   "5100826"	USPAT	2004/06/29 14:40
-	11	"5198384"   "5425392"   "5462638"	USPAT	2004/06/29 14:40
-	11		USPAT	2004/06/29 14:40

-	17	("4528066"   "4554050"   "4900690"   "5023201"   "5100826"   "5198384"   "5202287"   "5425392"   "5462638"   "5712168"   "5798296"   "5800726"   "5801425"   "5830798"   "5888894"	USPAT	2004/06/29 15:09
		"5960303"   "6136211").PN.		
-	49	(gate or word near line or wordline or transistor or fet or mosfet or sdram or rom or prom or dram) and (titanium or tungsten or metal) near2 (oxynitride or oxinitride or oxy-nitride) near5 (removal or removing or removed or remove or etch or etching or etched)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/29 15:24
-	36		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/29 15:32
-	75		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/29 15:34
-	27		USPAT;	2004/06/29 15:42
		(silicide or salicide) or tisi or wsi) same ((titanium or tungsten or ti or w) near (oxynitride or oxinitride or oxy-nitride or on or o near n)) same (etch or etching or etched or remove or removing or removal or removed)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
-	44	(memory or transistor or dram or sdram or rom or prom or mosfet or fet) and (gate near electrode) near6 (tungsten adj silicide or wsi or w adj si) near6 (titanium adj silicide or tisi or ti adj si)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/01 14:34

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